

2FI100G-100(2x100A)

FAST RECOVERY DIODE MODULE

1000V / 100A

2 in one-package

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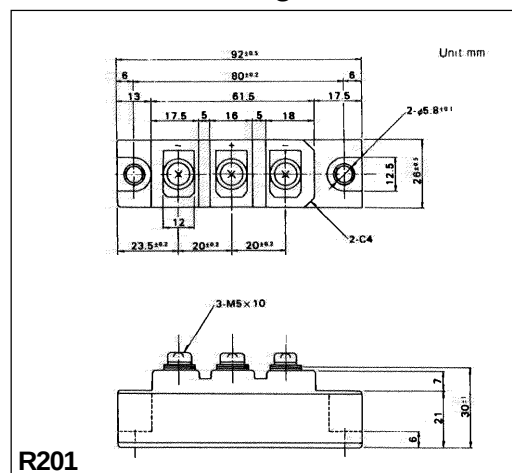
Features

- Short Reverse Recovery Time
- Variety of Connection Menu
- Insulated Type

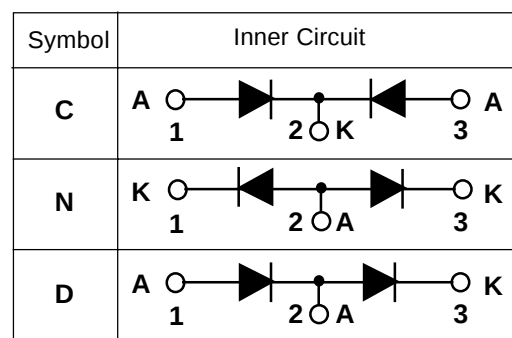
Applications

- Arc-Welders
- Free-Wheeling Diode
- High Speed Rectifiers

Outline Drawings, mm



Inner Circuit Schematic



Maximum ratings and characteristics

Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}		1000	V
Non-repetitive peak reverse voltage	V_{RSM}		1200	V
Average output current	$I_{F(AV)}$	50/60Hz Square wave, $T_c=82^{\circ}\text{C}$	2 x 100	A
Surge current	I_{FSM}	From rated load, Sine wave 10ms	1200	A
I^2t	I^2t	From rated load	5760	A^2s
Operating junction temperature	T_j		-40 to +150	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-40 to +150	$^{\circ}\text{C}$
Isolation voltage	V_{is}		AC2000(1min.)	V
Screw torque		(M5)	3.5 *1	N·m

*1: Recommendable value : 2.5 to 3.0 N·m(M5)

Electrical characteristics ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Forward voltage drop	V_{FM}	$T_j=25^{\circ}\text{C}$, $I_{FM}=100\text{A}$			1.65	V
Reverse current	I_{RRM}	$T_j=150^{\circ}\text{C}$, $V_R=V_{RRM}$			60	mA
Reverse recovery time	t_{rr}	$T_j=25^{\circ}\text{C}$, $I_F=I_R=0.1\text{A}$			0.6	μs

Thermal Characteristics

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Thermal resistance	$R_{th(j-c)}$	Junction to case			0.20	$^{\circ}\text{C/W}$
	$R_{th(c-f)}$	the base to cooling fin *			0.10	$^{\circ}\text{C/W}$

* : With Thermal Compound

time : t [sec.]	Thermal resistance : Zh(j-c) [°C/W]
10 ⁻³	0.15
10 ⁻²	0.25
10 ⁻¹	0.35
10 ⁰	0.40
10 ¹	0.40